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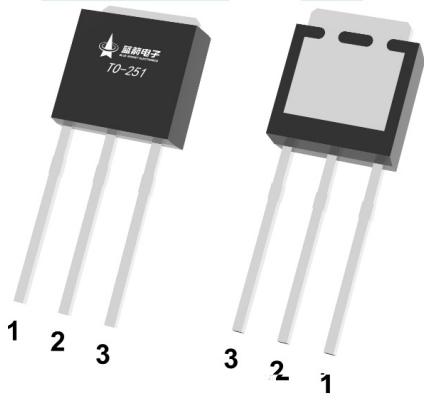
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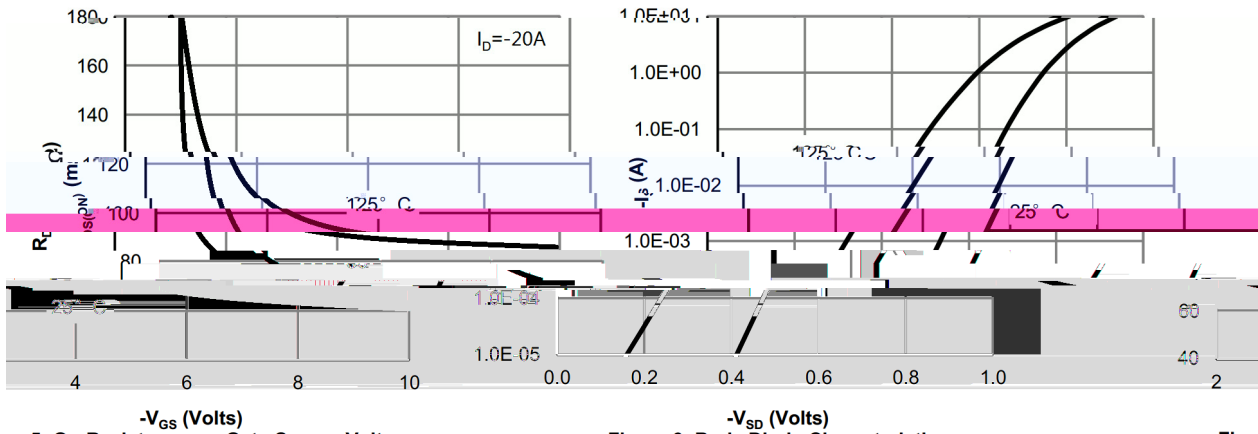
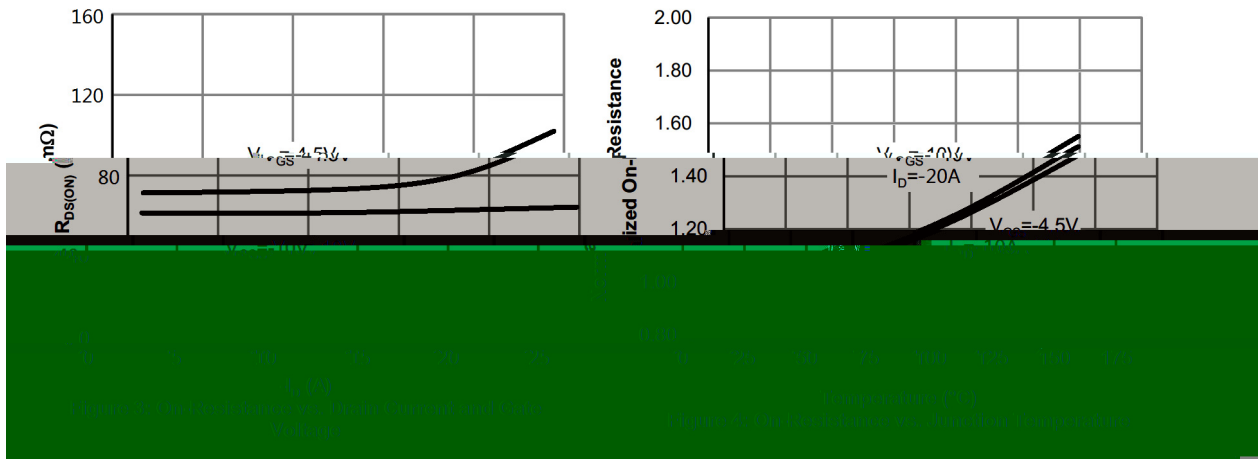
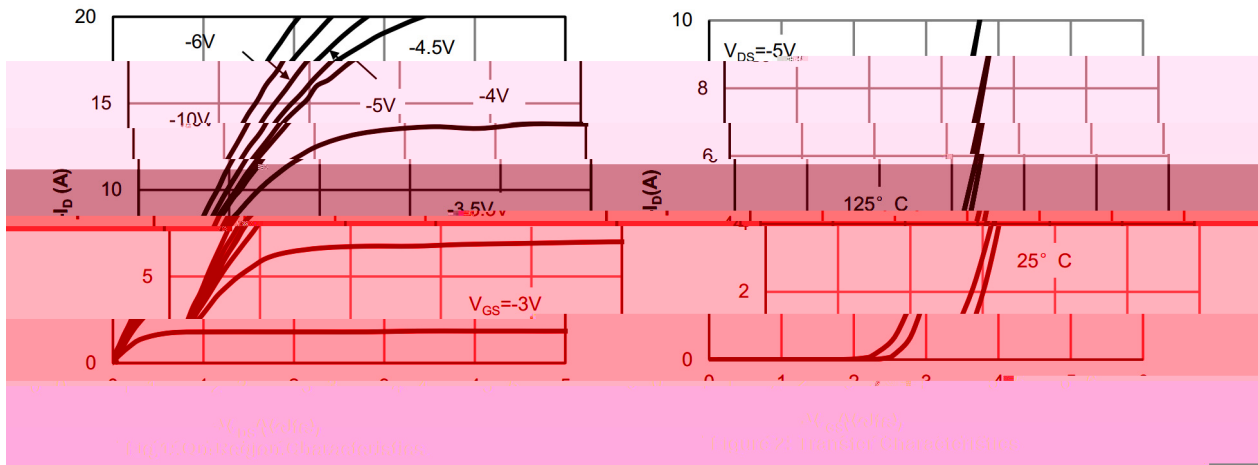


Figure 5: On-Resistance vs. Gate-Source Voltage

Figure 6: Body-Diode Characteristics

Figure 7: On-Resistance vs. Gate-Source Voltage

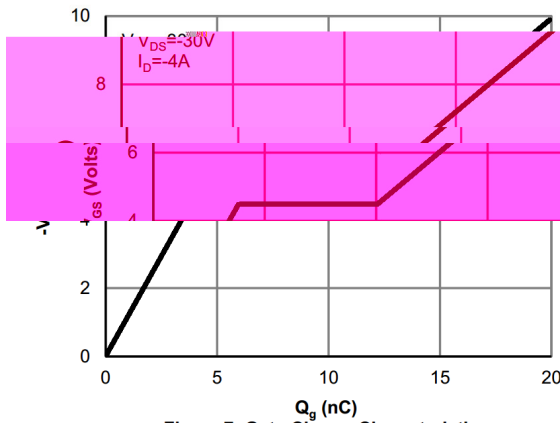


Figure 7: Gate-Charge Characteristics

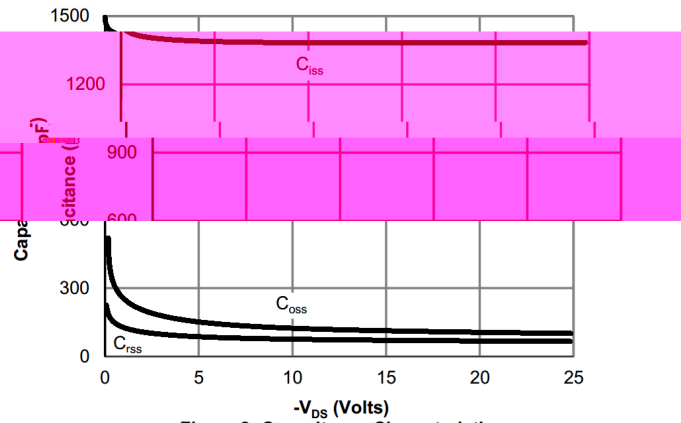


Figure 8: Capacitance Characteristics

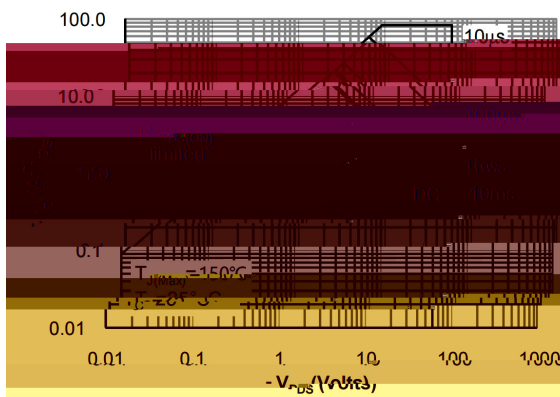


Figure 9: Maximum Forward Biased Safe Operating Area

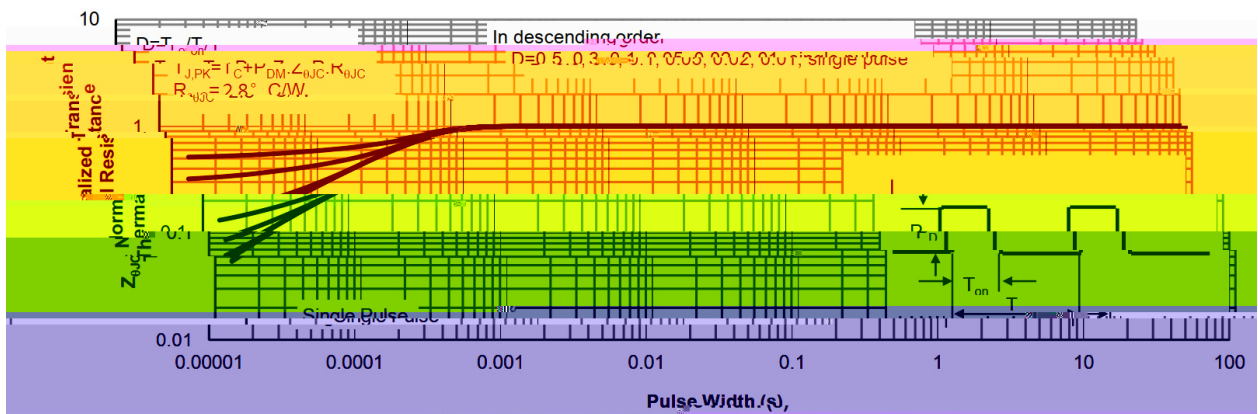
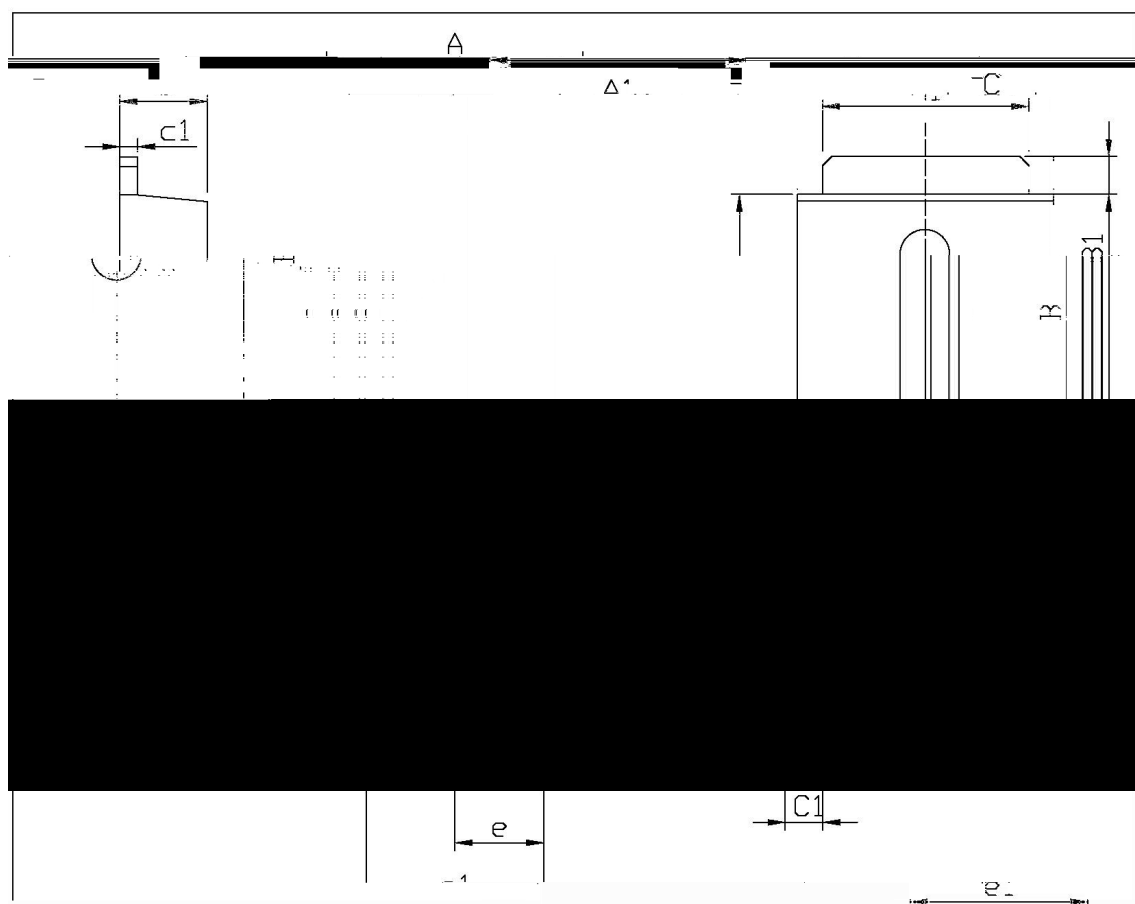


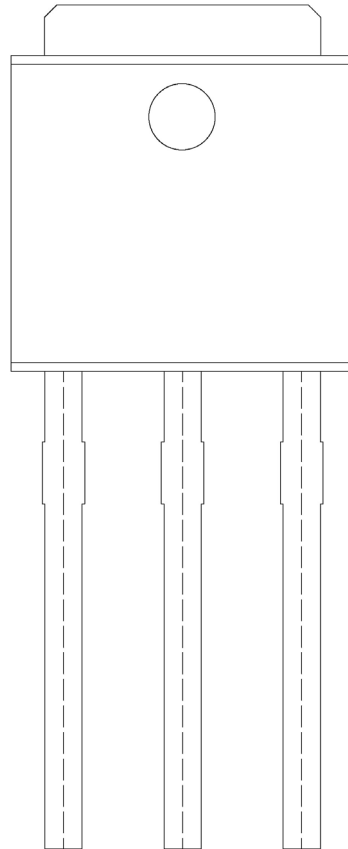
Figure 10: Normalized Maximum Transient Thermal Impedance

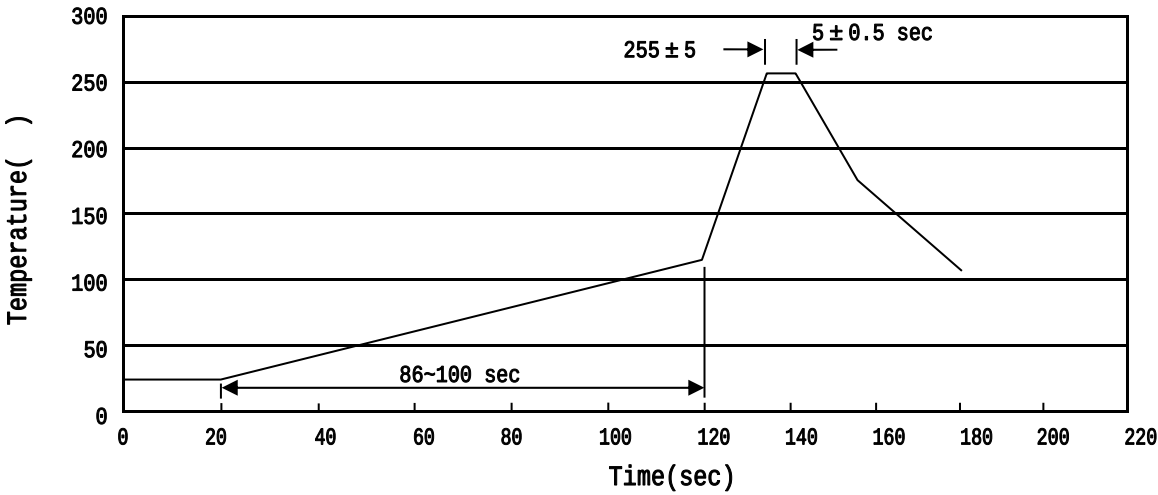


单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters		S
	Min	Max		Min	Max	
	6.40	6.75		0.50	0.50	
	5.10	5.50	b	9.00	9.40	
	5.95	6.25	c	0.45	0.55	
	B1	0.95	1.25	c1	0.45	0.55
	C	2.20	2.40	e	2.24	2.34
	4.73		C1	0.95	1.15	e1
						4.43

TQ-251





	Units/Bag /	Bags/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Bag	Inner Box	Outer Box

	Units/Tube /	Tubes/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Tube	Inner Box	Outer Box